NSN 5961-01-355-0505

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Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-355-0505 **Inclosure Material:** Ceramic **Mounting Facility Quantity: Component Name And Quantity:** 2 transistor **Mounting Method:** Slot **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 1200.0 breakdown voltage, collector-to-emitter, base open all transistor **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction Shelf Life: N/a **Unit Of Measure:** Demilitarization: No